



S/N 10/796,514

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: John P. Snyder, et al.

Examiner: Su C. Kim

Serial No.: 10/795,514 Conf. No.: 1961

Group Art Unit: 2823

Filed: March 9, 2004

Docket No.: 14467.05

Title: TRANSISTOR HAVING HIGH DIELECTRIC CONSTANT GATE INSULATING LAYER
AND SOURCE AND DRAIN FORMING SCHOTTKY CONTACT WITH SUBSTRATE

AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Applicants have carefully reviewed and considered the Office Action mailed on January 7, 2008, and the reference cited therewith. Please amend the above-identified patent application as follows. Applicants' Remarks follow the amendments.

This reply is being filed within **three** months of the mailing date of the Final Office Action. If necessary and not otherwise provided, please consider this a Petition for Extension of Time under 37 CFR 1.136(a) for filing these papers in the above-identified application. Please charge any necessary fee or credit overpayment to Deposit Account No. 502931.